

SYSTEM AND METHOD OF SENSING ACTUATION AND RELEASE VOLTAGES OF AN INTERFEROMETRIC MODULATOR

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Background

Field

The field of the invention relates to microelectromechanical systems (MEMS).

Description of the Related Technology

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Microelectromechanical systems (MEMS) include micro mechanical elements, actuators, and electronics. Micromechanical elements may be created using deposition, etching, and or other micromachining processes that etch away parts of substrates and/or deposited material layers or that add layers to form electrical and electromechanical devices. One type of MEMS device is called an interferometric modulator. An interferometric modulator may comprise a pair of conductive plates, one or both of which may be partially transparent and capable of relative motion upon application of an appropriate electrical signal. One plate may comprise a stationary layer deposited on a substrate, the other plate may comprise a metallic membrane suspended over the stationary layer. Such devices have a wide range of applications, and it would be beneficial in the art to utilize and/or modify the characteristics of these types of devices so that their features can be exploited in improving existing products and creating new products that have not yet been developed.

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Summary

The system, method, and devices of the invention each have several aspects, no single one of which is solely responsible for its desirable attributes. Without limiting the scope of this invention, its more prominent features will now be discussed briefly. After considering this discussion, and particularly after reading the section entitled "Detailed Description of Certain Embodiments" one will understand how the features of this invention provide advantages over other display devices.

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In one embodiment, the invention comprises a method of determining one or both of an actuation voltage and a release voltage of a microelectromechanical device. The method includes applying at least two different electric potentials to at least one electrode coupled to the device and detecting at least one electrical response of the device at the at least two different electric potentials. Based at least in part on the response, a state of the device at the at least two different

electric potentials is determined. Based at least in part on the determining a state one or both of the actuation voltage and release voltage are determined.

In another embodiment, a system for determining one or both of an actuation voltage and a release voltage of a microelectromechanical device includes means for applying at least two different electric potentials to at least one electrode coupled to the device and means for detecting at least one electrical response of the device at the at least two different electric potentials. Additionally provided are means for determining, based at least in part on the response, a state of the device at the at least two different electric potentials and means for determining one or both of the actuation voltage and release voltage based at least in part on the determining.

In another embodiment, a system for determining one or both of an actuation voltage and a release voltage of a microelectromechanical device includes a microelectromechanical device and a driving circuit configured to apply a voltage to the microelectromechanical device. A sensor connected to the a microelectromechanical device is configured for detecting at least one electrical response of the microelectromechanical device at the at least two different electric potentials. The sensor is further configured for determining, based at least in part on the response, a state of the device at the at least two different electric potentials and for determining one or both of the actuation voltage and release voltage based at least in part on the determining.

In another embodiment, a method of manufacturing a display system includes forming an array of microelectromechanical pixels configured to present display data to a user of the display system. The method includes, forming at least one additional microelectromechanical element; and coupling a sensor configured to sense one or both of an actuation voltage or a release voltage to the additional microelectromechanical element.

In another embodiment, a display system includes an array of microelectromechanical pixels configured to present display data to a user of the display system, at least one additional microelectromechanical element, and a sensor. The sensor is configured to sense one or both of an actuation voltage or a release voltage of the additional microelectromechanical pixel.

In another embodiment, a display system includes means for displaying data to a user of a display system and at least one microelectromechanical element. Also provided are means for detecting one or both of an actuation voltage or a release voltage of the microelectromechanical element.

In another embodiment, a method of manufacturing a system for determining one or both of an actuation voltage and a release voltage of a microelectromechanical device includes forming a microelectromechanical device and coupling a driving circuit configured to apply a voltage to the microelectromechanical device. The method also includes coupling a sensor to the a microelectromechanical device, the sensor is configured for detecting at least one electrical response of the microelectromechanical device at the at least two different electric potentials, and

is further configured for determining, based at least in part on the response, a state of the device at the at least two different electric potentials. The sensor also determines one or both of the actuation voltage and release voltage based at least in part on the determining.

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Brief Description of the Drawings

Figure 1 is an isometric view depicting a portion of one embodiment of an interferometric modulator display in which a movable mirror of a first interferometric modulator is in a reflective, or “on,” position at a predetermined distance from a fixed mirror and the movable mirror of a second interferometric modulator is in a non-reflective, or “off” position.

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Figure 2 is a system block diagram illustrating one embodiment of an electronic device incorporating a 3x3 interferometric modulator display.

Figure 3A is a diagram of movable mirror position versus applied voltage for one exemplary embodiment of an interferometric modulator of Figure 1.

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Figure 3B is an illustration of sets of row and column voltages that may be used to drive an interferometric modulator display.

Figure 4A illustrates one exemplary frame of display data in the 3x3 interferometric modulator display of Figure 2.

Figure 4B illustrates one exemplary timing diagram for row and column signals that may be used to write the frame of Figure 4A.

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Figure 5A is a cross section of the device of Figure 1.

Figure 5B is a cross section of an alternative embodiment of an interferometric modulator.

Figure 5C is a cross section of an alternative embodiment of an interferometric modulator

Figure 6 is a schematic/block diagram of one embodiment of a state sensing circuit.

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Figure 7 is graph illustrating a voltage vs. time response to a voltage pulse for an interferometric modulator.

Figure 8 is a schematic/block diagram of another embodiment of a state sensing circuit

Figure 9 is graph illustrating a current vs. time response to a voltage pulse for an interferometric modulator.

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Figure 10 is a flow chart of a state sensing process.

Figure 11 is a timing diagram illustrating row and column voltages for setting and testing a row of interferometric modulators.

Figure 12 is a block diagram of a state sensing apparatus for modulators embedded in arrays.

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Figure 13 is a flow chart of another embodiment of a state sensing process.

Figure 14 is a block diagram of a display incorporating test pixels.

Figure 15 is a graph of voltage versus time applied to a pixel which may be used to determine the actuation and release voltages of an interferometric modulator.

Figure 16 is a schematic of a circuit which may be used to determine the actuation and release voltages used with the voltage versus time voltage application of Figure 15.

5 Figure 17 is a graph illustrating the timing of the circuit of Figure 16.

Figure 18 is a graph of another embodiment of a voltage versus time applied to a pixel and current versus time response which may be used to determine the actuation and release voltages of an interferometric modulator.

10 Figure 19 is a schematic of a circuit which may be used to determine the actuation and release voltages with the voltage versus time voltage application of Figure 18.

Figure 20 is a schematic of another embodiment of a circuit which may be used to determine the actuation and release voltages of an interferometric modulator.

Figures 21A and 21B are system block diagrams illustrating an embodiment of a visual display device comprising a plurality of interferometric modulators.

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Detailed Description of Preferred Embodiments

The following detailed description is directed to certain specific embodiments of the invention. However, the invention can be embodied in a multitude of different ways as defined and covered by the claims. In this description, reference is made to the drawings wherein like parts are designated with like numerals throughout.

20 Embodiments of the invention may be implemented in any device that is configured to display an image, whether in motion (e.g., video) or stationary (e.g., still image), and whether textual or pictorial. More particularly, it is contemplated that the invention may be implemented in or associated with a variety of electronic devices such as, but not limited to, mobile telephones, wireless devices, personal data assistants (PDAs), hand-held or portable computers, electronic books, GPS receivers/navigators, cameras, MP3 players, camcorders, game consoles, wrist watches, clocks, calculators, television monitors, flat panel displays, computer monitors, auto displays (e.g., odometer display, etc.), cockpit controls and/or displays, display of camera views (e.g., display of a rear view camera in a vehicle), electronic photographs, electronic billboards or signs, projectors, architectural structures, packaging, and aesthetic structures (e.g., display of images on a piece of jewelry).

MEMS devices of similar structure to those described herein can also be used in non-display applications such as in electronic switching devices.

One interferometric modulator display embodiment comprising an interferometric MEMS display element is illustrated in Figure 1. In these devices, the pixels are in either a bright or dark state. In the bright ("on" or "open") state, the display element reflects a large

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portion of incident visible light to a user. When in the dark (“off” or “closed”) state, the display element reflects little incident visible light to the user. Depending on the embodiment, the light reflectance properties of the “on” and “off” states may be reversed. MEMS pixels can be configured to reflect predominantly at selected colors, allowing for a color display in addition to black and white.

Figure 1 is an isometric view depicting two adjacent pixels in a series of pixels of a visual display, wherein each pixel comprises a MEMS interferometric modulator. In some embodiments, an interferometric modulator display comprises a row/column array of these interferometric modulators. Each interferometric modulator includes a pair of reflective layers positioned at a variable and controllable distance from each other to form a resonant optical cavity with at least one variable dimension. In one embodiment, one of the reflective layers may be moved between two positions. In the first position, referred to herein as the released state, the movable layer is positioned at a relatively large distance from a fixed partially reflective layer. In the second position, the movable layer is positioned more closely adjacent to the partially reflective layer. Incident light that reflects from the two layers interferes constructively or destructively depending on the position of the movable reflective layer, producing either an overall reflective or non-reflective state for each pixel.

The depicted portion of the pixel array in Figure 1 includes two adjacent interferometric modulators 12a and 12b. In the interferometric modulator 12a on the left, a movable and highly reflective layer 14a is illustrated in a released position at a predetermined distance from a fixed partially reflective layer 16a. In the interferometric modulator 12b on the right, the movable highly reflective layer 14b is illustrated in an actuated position adjacent to the fixed partially reflective layer 16b.

The fixed layers 16a, 16b are electrically conductive, partially transparent and partially reflective, and may be fabricated, for example, by depositing one or more layers each of chromium and indium-tin-oxide onto a transparent substrate 20. The layers are patterned into parallel strips, and may form row electrodes in a display device as described further below. The movable layers 14a, 14b may be formed as a series of parallel strips of a deposited metal layer or layers (orthogonal to the row electrodes 16a, 16b) deposited on top of posts 18 and an intervening sacrificial material deposited between the posts 18. When the sacrificial material is etched away, the deformable metal layers are separated from the fixed metal layers by a defined air gap 19. A highly conductive and reflective material such as aluminum may be used for the deformable layers, and these strips may form column electrodes in a display device.

With no applied voltage, the cavity 19 remains between the layers 14a, 16a and the deformable layer is in a mechanically relaxed state as illustrated by the pixel 12a in Figure 1. However, when a potential difference is applied to a selected row and column, the capacitor

formed at the intersection of the row and column electrodes at the corresponding pixel becomes charged, and electrostatic forces pull the electrodes together. If the voltage is high enough, the movable layer is deformed and is forced against the fixed layer (a dielectric material which is not illustrated in this Figure may be deposited on the fixed layer to prevent shorting and control the separation distance) as illustrated by the pixel 12b on the right in Figure 1. The behavior is the same regardless of the polarity of the applied potential difference. In this way, row/column actuation that can control the reflective vs. non-reflective pixel states is analogous in many ways to that used in conventional LCD and other display technologies.

Figures 2 through 4B illustrate one exemplary process and system for using an array of interferometric modulators in a display application. Figure 2 is a system block diagram illustrating one embodiment of an electronic device that may incorporate aspects of the invention. In the exemplary embodiment, the electronic device includes a processor 21 which may be any general purpose single- or multi-chip microprocessor such as an ARM, Pentium®, Pentium II®, Pentium III®, Pentium IV®, Pentium® Pro, an 8051, a MIPS®, a Power PC®, an ALPHA®, or any other suitable processor. In addition, the processor 21 may comprise any special purpose microprocessor such as a digital signal processor, microcontroller, or a programmable gate array. As is conventional in the art, the processor 21 may be configured to execute one or more software modules. In addition to executing an operating system (not shown), the processor may be configured to execute one or more software applications, including a web browser, a telephone application, an email program, or any other software application. It will be appreciated that all of the functionality described herein may be implemented in whole or part in hardware, software, or a combination thereof.

In one embodiment, the processor 21 is also configured to communicate with an array controller 22. In one embodiment, the array controller 22 includes a row driver circuit 24 and a column driver circuit 26 that provide signals to the array 30. The cross section of the array illustrated in Figure 1 is shown by the lines 1-1 in Figure 2. The array control 22 may also include a boost circuit 32 for converting control signals to a voltage or voltages sufficient for driving the array 30. In one embodiment, the display control 22 also includes a frame buffer 34. The frame buffer typically includes sufficient memory to store the current displayed frame for refresh purposes.

A plurality of tri-state buffers 36 are advantageously provided on each of the columns and each of the rows of array 30. The tri-state buffers 36 are connected to hold-mode signals which open the connection to the respective row or column of the array when they are asserted. When the hold-mode select lines are asserted, lines from the driver to the array are opened, substantially eliminating any leakage path for the charge stored on each pixel capacitance. The pixels are thus held in the previously charged or discharged state without any driver input, until

the charge slowly dissipates, either through leakage across the pixel or through a non-infinite tri-state open resistance. It will be appreciated that any controllable series switch such as a series FET could be used to implement this display/driver decoupling.

For MEMS interferometric modulators, the row/column actuation protocol may take advantage of a hysteresis property of these devices illustrated in Figure 3A. It may require, for example, a 10 volt potential difference to cause a movable layer to deform from the released state to the actuated state. However, when the voltage is reduced from that value, the movable layer maintains its state as the voltage drops back below 10 volts. In the exemplary embodiment of Figure 3A, the movable layer does not release completely until the voltage drops below 2 volts. There is thus a range of voltage, about 3 to 7 V in the example illustrated in Figure 3A, where there exists a window of applied voltage within which the device is stable in either the released or actuated state. This is referred to herein as the "hysteresis window" or "stability window." For a display array having the hysteresis characteristics of Figure 3A, the row/column actuation protocol can be designed such that during row strobing, pixels in the strobed row that are to be actuated are exposed to a voltage difference of about 10 volts, and pixels that are to be released are exposed to a voltage difference of close to zero volts. After the strobe, the pixels are exposed to a steady state voltage difference of about 5 volts such that they remain in whatever state the row strobe put them. After being written, each pixel sees a potential difference within the "stability window" of 3-7 volts in this example. This feature makes the pixel design illustrated in Figure 1 stable under the same applied voltage conditions in either an actuated or released pre-existing state. Since each pixel of the interferometric modulator, whether in the actuated or released state, is essentially a capacitor formed by the fixed and moving reflective layers, this stable state can be held at a voltage within the hysteresis window with almost no power dissipation. Essentially no current flows into the pixel if the applied potential is fixed.

In typical applications, a display frame may be created by asserting the set of column electrodes in accordance with the desired set of actuated pixels in the first row. A row pulse is then applied to the row 1 electrode, actuating the pixels corresponding to the asserted column lines. The asserted set of column electrodes is then changed to correspond to the desired set of actuated pixels in the second row. A pulse is then applied to the row 2 electrode, actuating the appropriate pixels in row 2 in accordance with the asserted column electrodes. The row 1 pixels are unaffected by the row 2 pulse, and remain in the state they were set to during the row 1 pulse. This may be repeated for the entire series of rows in a sequential fashion to produce the frame. Generally, the frames are refreshed and/or updated with new display data by continually repeating this process at some desired number of frames per second. A wide variety of protocols for driving row and column electrodes of pixel arrays to produce display frames are also well known and may be used in conjunction with the present invention.

Figures 3B, 4A and 4B illustrate one possible actuation protocol for creating a display frame on the 3x3 array of Figure 2. Figure 3B illustrates a possible set of column and row voltage levels that may be used for pixels exhibiting the hysteresis curves of Figure 3A. In the Figure 3B embodiment, actuating a pixel involves setting the appropriate column to $-V_{\text{bias}}$, and the appropriate row to $+\Delta V$, which may correspond to -5 volts and +5 volts respectively. Releasing the pixel is accomplished by setting the appropriate column to $+V_{\text{bias}}$, and the appropriate row to the same $+\Delta V$, producing a zero volt potential difference across the pixel. In those rows where the row voltage is held at zero volts, the pixels are stable in whatever state they were originally in, regardless of whether the column is at $+V_{\text{bias}}$ or $-V_{\text{bias}}$.

Figure 4B is a timing diagram showing a series of row and column signals applied to the 3x3 array of Figure 2 which will result in the display arrangement illustrated in Figure 4A, where actuated pixels are non-reflective. Prior to writing the frame illustrated in Figure 4A, the pixels can be in any state, and in this example, all the rows are at 0 volts, and all the columns are at +5 volts. With these applied voltages, all pixels are stable in their existing actuated or released states.

In the Figure 4A frame, pixels (1,1), (1,2), (2,2), (3,2) and (3,3) are actuated. To accomplish this, during a "line time" for row 1, columns 1 and 2 are set to -5 volts, and column 3 is set to +5 volts. This does not change the state of any pixels, because all the pixels remain in the 3-7 volt stability window. Row 1 is then strobed with a pulse that goes from 0, up to 5 volts, and back to zero. This actuates the (1,1) and (1,2) pixels and releases the (1,3) pixel. No other pixels in the array are affected. To set row 2 as desired, column 2 is set to -5 volts, and columns 1 and 3 are set to +5 volts. The same strobe applied to row 2 will then actuate pixel (2,2) and release pixels (2,1) and (2,3). Again, no other pixels of the array are affected. Row 3 is similarly set by setting columns 2 and 3 to -5 volts, and column 1 to +5 volts. The row 3 strobe sets the row 3 pixels as shown in Figure 5A. After writing the frame, the row potentials are zero, and the column potentials can remain at either +5 or -5 volts, and the display is then stable in the arrangement of Figure 4A. It will be appreciated that the same procedure can be employed for arrays of dozens or hundreds of rows and columns. It will also be appreciated that the timing, sequence, and levels of voltages used to perform row and column actuation can be varied widely within the general principles outlined above, and the above example is exemplary only, and any actuation voltage method can be used with the present invention.

The details of the structure of interferometric modulators that operate in accordance with the principles set forth above may vary widely. For example, Figures 5A-5C illustrate three different embodiments of the moving mirror structure. Figure 5A is a cross section of the embodiment of Figure 1, where a strip of metal material 14 is deposited on orthogonally extending supports 18. In Figure 5B, the moveable reflective material 14 is attached to supports

at the corners only, on tethers 38. In Figure 5C, the moveable reflective material 14 is suspended from a deformable layer 40. This embodiment has benefits because the structural design and materials used for the reflective material 14 can be optimized with respect to the optical properties, and the structural design and materials used for the deformable layer 40 can be optimized with respect to desired mechanical properties. The production of various types of interferometric devices is described in a variety of published documents, including, for example, U.S. Published Application 2004/0051929. A wide variety of well known techniques may be used to produce the above described structures involving a series of material deposition, patterning, and etching steps.

After a pixel is written, it can be advantageous to sense its state. For the bi-stable display of Figure 1, the state of a pixel can be determined by taking advantage of the fact that the capacitance across the pixel mirrors is much larger, often about ten times larger, when the pixels are in the actuated state than when they are in the released state. This pixel capacitance value can be sensed in a variety of ways by sensing capacitance dependent electrical properties of the pixel, some of which are described in more detail below.

The principles of pixel state sensing will be described first with reference to a single pixel in isolation as illustrated in Figures 6-10. Referring now to Figure 6, after pixel writing, whether the whole frame is complete or prior to that time, all the column tri-state buffers can be placed in the open (decoupled) configuration except one column containing the pixel to be tested. The row driver then applies a low amplitude pulse to the row electrode containing the pixel to be tested, which charges up in response to the increased voltage. As shown in Figure 7, the voltage across the pixel will increase in response to this applied voltage in accordance with the RC time constant (τ) of the circuit. For a single pixel in isolation, the capacitance is the capacitance of the pixel 54, and the resistance of the circuit may include the row driver output impedance and/or any filter resistor 56 that might be placed in series with the row electrode. The voltage at the test point 58 when the pixel 54 is in a low capacitance state (e.g. in the released state) will increase faster as illustrated by curve 60 than when the pixel 54 is in a high capacitance state (e.g. in the actuated state) as illustrated by curve 62. If the voltage across the pixel is determined at a certain time during this charging period, at $\tau/3$ for example, the state of the pixel can be determined. This voltage can be detected and measured by a voltage sensing circuit 64. If a pulse having a duration of $\tau/3$ is applied to the pixel, the voltage across the pixel will increase and decrease as shown in the trace 66 (also shown in Figure 7). If this signal is applied to the input of a comparator 68 with V_{thresh} applied to the negative input, a pulse will be output from the comparator only if the voltage across the pixel exceeded V_{thresh} at some time during the pulse, where V_{thresh} is defined as shown in Figure 7. The output of the comparator 68 can be latched to produce an indication of whether that pixel is actuated (latch low) or released (latch high).

Figures 8 and 9 illustrate an alternative method of detecting pixel state. In Figure 8, a current sensing circuit 70 is used rather than a voltage sensing circuit. A voltage pulse is applied as above, which causes a current pulse as the pixel capacitance charges. As illustrated in Figure 9, this current pulse decays slower (curve 75) for a larger capacitance of pixel 54 than for a smaller capacitance (curve 77). The current pulse can be converted to a voltage pulse by measuring the voltage across a series resistance 72 in the column line (amplifiers configured as current to voltage converters could also be used). The voltage across the resistor can be sensed by an amplifier configured as an integrator 74 illustrated in Figure 8. The output of the integrator can be routed to a similar comparator 76 and latch as in Figure 6. The comparator 76 will only produce an output pulse if the current pulse through the circuit is sufficient (given the value of the resistor 72 and the time constant/amplification of the integrator 74) to produce a voltage at the comparator input greater than a threshold voltage V_{thresh2} shown in Figure 8. Figure 8 shows a switch 78 used to switch resistance 72 into the column line, but it will be appreciated that this would not be necessary if a suitable filter resistor, for example, was already present.

Current sensing requires a slightly more complicated circuit than voltage sensing, but one advantage would be that all the pixels in a row could be probed by a single pulse since the charging current could be separately measured for each pixel along a row simultaneously with separate current sensors. In these embodiments, there may be a sensor dedicated to each column, or a set of current sensors could be sequentially switched between different groups of columns such that a portion, but not all of the column currents are sensed concurrently. This last embodiment would be slower than an embodiment with a sensor for every row, but faster than one at a time sensing.

In accordance with the principles above, Figure 10 is a flowchart illustrating an exemplary process for determining an open or closed state of an interferometric modulator. A test pulse is applied to the pixel at step 80. At step 82, a capacitance dependent response to the pulse is measured. At step 84, the response is compared to a threshold to determine the state of the pixel.

Pixel state sensing can be advantageous for a variety of reasons. For example, on the next frame update or refresh, only those pixels that are different from the next desired frame need be updated. For a static display, the pixel states may be monitored to detect which pixels have relaxed from an actuated state to a released state due to charge leakage. Selective updating could be performed in a variety of ways. For example, once one or more pixels change from the desired state, the driver circuitry could be turned back on, the tri-state buffers closed, and row strobing could be limited to only those rows which include pixels in an undesired state. Other rows could be skipped. This reduces the total energy required to update the display. Pixel state sensing could also be advantageous during the frame writing process, because as rows of pixels

are written, they could be checked to determine if they were written correctly or not. If not, the row could be written again until correct. Pixel state sensing can also advantageously minimize the peak memory requirements for the frame buffer.

An implementation of this last process is illustrated in Figure 11. After writing row 1 during the row 1 line time 90, a row 1 test time 92 is entered. In the first portion of this time period, only row 1 and column 1 are connected to the drive circuitry, and a test pulse 94 of about 1 volt or less is applied to row 1. As described above, the capacitance dependent response of pixel (1,1) is monitored to be sure it is in the actuated state as shown in Figure 5A. This is repeated for pixels (1,2) and (1,3) during subsequent portions of the row 1 test time. The system then enters the row 2 line time, or alternatively, repeats the row 1 line time if it is determined that one or more pixels in row 1 have not been correctly written. For purposes of illustration, the test voltage amplitude is shown larger than generally desired and the test time period is shown much longer than would normally be necessary, as the pulse time periods for testing can be very short compared to the pulse periods used to actuate the pixels during the write process. When the pixel 54 being tested is part of a large array of tightly packed pixels, the testing process may be somewhat more complex. This is because the test pulse is applied to an entire row of pixels. Thus, the time constant of the charging process is dependent on the capacitance between the entire row electrode and the return column electrode, and this can be affected by the relative states of all the pixels in the row, not just on the state of the pixel being tested 54, shown again in Figure 12. The dominant factor in the capacitance will be the state of the pixel being tested, but since there may be hundreds of pixels in the row, the combined effect of the remainder can be significant. There can also be capacitive coupling between pixels in different rows that share the same column electrode. The practical effect of this is that it may be advantageous to vary the pulse time period $\tau/3$, the V_{thresh} value, or both, when testing pixels in a given row, depending on the states of the other pixels in the row.

This determination can be done in several ways. One embodiment illustrated in Figure 12 can include in each row, at the end of the row outside the viewed area of the display, a test pixel 98. This pixel can be switched between states, and the rise times for the test pulse can be determined for both the actuated and released states. In this way, the time period having the maximum voltage difference between states, and the voltage values between which V_{thresh} should be located could be determined based on the test pixel response. These values could then be used to test the state of the other pixels in the row.

Alternatively, a filter resistor could be placed at the end of the row instead of a test pixel. A collective capacitance measurement for the whole row electrode could then be made. The drive control circuitry could use this information to compute or look up an appropriate value for $\tau/3$, V_{thresh} , or both, to test the pixels in that row.

A general state sensing process using these principles for pixels embedded in arrays of rows and columns is illustrated in Figure 13. At step 102, row measurement signals are applied to a row containing a pixel to be sensed. These signals could involve testing a test pixel or an overall row capacitance measurement as described above. At step 104, appropriate test parameters such as period $\tau/3$ and/or V_{thresh} are determined for later pixel testing in the row. As in Figure 10, a test pulse is then applied to the row at step 106. At step 108, a capacitance dependent response to the pulse is measured. At step 110, the response is compared to a threshold to determine the state of a selected pixel in the row.

Pulse amplitudes and durations for the pixel state sensing process may be selected based on a variety of desired factors. The pulse may be shaped to control the total charge injected into the row. For isolated pixels, the pulse current and time profile can be defined such that a pre-selected charge is injected into the pixel regardless of its capacitance value. In this case, the resulting voltage across the pixel will be inversely proportional to the pixel capacitance. It may be possible to use this method for pixels in an array as well, but its usefulness may be limited since the charge injected into the row may be distributed throughout the hundreds of row pixels in a way that is complicated and difficult to predict. Pulse durations may be selected based on the circuit τ value, with short pulses preferred for time savings. It is of course desirable that the potential applied to the pixel during this process remains at all times within the hysteresis window so that the state sensing process does not itself change the state of the pixel being sensed. Thus, the driver will advantageously supply the appropriate bias voltage when not applying a charging pulse and when not decoupled by the tri-state amplifiers, and will generate pulses deviating from this bias voltage that are small enough (e.g. no more than 1 or 2 volts typically) such that the applied pixel voltages are never outside of the hysteresis window.

Another advantageous application of pixel state sensing is for determining the actuation and release voltages of a pixel. This can be useful because these voltages are temperature dependent, and may shift over time as well. Higher temperatures tend to shift the stability window of Figure 3A closer to zero for metal mirrors on glass substrates. Depending on the relative coefficients of thermal expansion of the material layers, shifts of either direction as a function of temperature can occur. If pixel actuation and release voltages can be determined electrically, the drive voltages used to write image data to an array of pixels can be modified to match the current pixel behavior. A display incorporating this feature is illustrated in Figure 14. In this embodiment, extra test pixels 112 are placed around the actual viewing area of the display 114. These test pixels may be fabricated during the same process that produces the display so that the physical characteristics are similar if not essentially identical with the physical characteristics of the pixels in the viewed display area 114. One or more sense circuits 118 that

apply variable bias voltages and test voltages are coupled to the test pixels. It will be appreciated that some or all of the sense circuitry could be shared among multiple test pixels.

With separate test pixels, a variety of sensing protocols can be implemented to determine the actuation and/or the release voltages of a capacitive MEMS pixel. For example, this determination can be performed by applying a series of voltages across a pixel, and sensing the state at each applied voltage. This is illustrated in Figure 15. The voltage can be stepped up from zero to a voltage that is above the expected actuation voltage under all conditions. At each voltage level, a pixel state test as described above may be performed to determine the pixel state. At some voltage level, the pixel will actuate, and this will be detected during the test. Pixel voltage can then be stepped down and tested at each level back down to zero. At some voltage level, the pixel will release, and this will again be detected by the test results.

In Figure 15, the voltage step is one volt for each step, but it will be appreciated that any step size may be used. During each step, after the pixel has charged from the previous voltage transition, a test pulse 120 is applied as described above. The appropriate voltages or currents are monitored as desired, and the pixel state is determined at each voltage level. Ranges for the actuation and release voltages can be determined by determining which step caused a state change. Advantageously, the amplitude and duration of the test pulses are less than the step size and duration.

Figures 16 and 17 illustrate a circuit and its operation that can implement the method of Figure 15. In this embodiment, a test pulse is added to a series of stepped up and stepped down voltages and the signal sum is applied to one side of a pixel. The other side is grounded with an inverting current to voltage converter 124. A switch 126 connects the output of the current to voltage converter to the input of a comparator 128. As shown in Figure 17, the CLK1 signal attached to the test pulse generator produces the test pulse duration. As illustrated in Figure 9 and described above, the test pulse produces a current pulse through the test pixel that decays much slower for an actuated pixel than for a released pixel. The CLK2 signal controls the connection between the output of the current to voltage converter 124 and the input to the comparator 128. The input to the comparator is pulled low by resistor 130 when the switch 126 is open. The CLK2 signal is timed to have a rising edge delayed from the rising edge of CLK1 and have a short duration to sample the voltage output from the current to voltage converter 124 at a selected point in time during the charging process. This voltage will be higher for an actuated pixel than for a released pixel. If the voltage is more negative than $-V_{thres3}$ (negative because of the inverting amplifier 124) during the CLK2 sample period, this indicates an actuated pixel, and the output of the comparator 128 will be high during the sample period. This is repeated sequentially for each test pulse, and the series of comparator outputs are shifted into a shift register 136 at times determined by signal CLK3 which is within the assertion time of

CLK2. The outputs of the shift register 136 then form a record of the actuated vs. released state of the pixel at each level on the way up and back down.

Figures 18 and 19 illustrate another circuit implementation that can be used to determine actuation and release voltages of a bistable pixel. If the voltage on the pixel is increased at a rate that is slow compared to the pixel RC charging time constant and the time it takes for a pixel to switch between states, the current will be very low while the voltage is ramped up. This will be true until the pixel changes to the actuated state and the capacitance quickly increases. This will cause a current pulse to flow during the transition to a high capacitance state. On the ramp back downward, a second current pulse in the opposite direction (quickly reducing the charge on the pixel capacitance) will occur.

These current pulses can be detected by the circuit of Figure 19. In this embodiment, the output of the current to voltage converter 124 is coupled to a pair of comparators 140 and 142. Both comparator outputs will both be low when the charging current is small. During the first current pulse, the output of comparator 140 will go high. During the second current pulse, the output of comparator 142 will go high. The time at which these pulses occur can be determined by having each output pulse from the comparators stop a respective counter 144, 146 that is started at the same time the ramp is started. The counter values can be associated with the actuation and release voltages because the voltage as a function of time of the applied voltage ramp is known.

Another possible test circuit is illustrated in Figure 20. In this embodiment, an AC signal is placed on top of a DC bias voltage and is applied to the pixel at node 150. More AC current will flow through the pixel when the pixel is actuated than when it is released. This AC current can be detected by including both a DC coupled path to ground and an AC coupled path to ground on the other plate of the pixel. The DC voltage across capacitor 154 will increase with increasing AC current through the pixel and through capacitor 156. This voltage is routed to a comparator 158, which goes high if this value is above $V_{thresh6}$, which is determined based on the component values. In this embodiment, the DC bias voltage can be varied in any manner, and the output 160 of the comparator 158 will be high when the pixel is actuated, and low when the pixel is released.

Figures 21A and 21B are system block diagrams illustrating an embodiment of a display device 2040. The display device 2040 can be, for example, a cellular or mobile telephone. However, the same components of display device 2040 or slight variations thereof are also illustrative of various types of display devices such as televisions and portable media players.

The display device 2040 includes a housing 2041, a display 2030, an antenna 2043, a speaker 2045, an input device 2048, and a microphone 2046. The housing 2041 is generally formed from any of a variety of manufacturing processes as are well known to those of skill in

the art, including injection molding, and vacuum forming. In addition, the housing 2041 may be made from any of a variety of materials, including but not limited to plastic, metal, glass, rubber, and ceramic, or a combination thereof. In one embodiment the housing 2041 includes removable portions (not shown) that may be interchanged with other removable portions of different color, or containing different logos, pictures, or symbols.

The display 2030 of exemplary display device 2040 may be any of a variety of displays, including a bi-stable display, as described herein. In other embodiments, the display 2030 includes a flat-panel display, such as plasma, EL, OLED, STN LCD, or TFT LCD as described above, or a non-flat-panel display, such as a CRT or other tube device, as is well known to those of skill in the art. However, for purposes of describing the present embodiment, the display 2030 includes an interferometric modulator display, as described herein.

The components of one embodiment of exemplary display device 2040 are schematically illustrated in Figure 21B. The illustrated exemplary display device 2040 includes a housing 2041 and can include additional components at least partially enclosed therein. For example, in one embodiment, the exemplary display device 2040 includes a network interface 2027 that includes an antenna 2043 which is coupled to a transceiver 2047. The transceiver 2047 is connected to the processor 2021, which is connected to conditioning hardware 2052. The conditioning hardware 2052 may be configured to condition a signal (e.g. filter a signal). The conditioning hardware 2052 is connected to a speaker 2045 and a microphone 2046. The processor 2021 is also connected to an input device 2048 and a driver controller 2029. The driver controller 2029 is coupled to a frame buffer 2028 and to the array driver 2022, which in turn is coupled to a display array 2030. A power supply 2050 provides power to all components as required by the particular exemplary display device 2040 design.

The network interface 2027 includes the antenna 2043 and the transceiver 2047 so that the exemplary display device 2040 can communicate with one or more devices over a network. In one embodiment the network interface 2027 may also have some processing capabilities to relieve requirements of the processor 2021. The antenna 2043 is any antenna known to those of skill in the art for transmitting and receiving signals. In one embodiment, the antenna transmits and receives RF signals according to the IEEE 802.11 standard, including IEEE 802.11(a), (b), or (g). In another embodiment, the antenna transmits and receives RF signals according to the BLUETOOTH standard. In the case of a cellular telephone, the antenna is designed to receive CDMA, GSM, AMPS or other known signals that are used to communicate within a wireless cell phone network. The transceiver 2047 pre-processes the signals received from the antenna 2043 so that they may be received by and further manipulated by the processor 2021. The transceiver 2047 also processes signals received from the processor 2021 so that they may be transmitted from the exemplary display device 2040 via the antenna 2043.

In an alternative embodiment, the transceiver 2047 can be replaced by a receiver. In yet another alternative embodiment, network interface 2027 can be replaced by an image source, which can store or generate image data to be sent to the processor 2021. For example, the image source can be a digital video disc (DVD) or a hard-disc drive that contains image data, or a software module that generates image data.

Processor 2021 generally controls the overall operation of the exemplary display device 2040. The processor 2021 receives data, such as compressed image data from the network interface 2027 or an image source, and processes the data into raw image data or into a format that is readily processed into raw image data. The processor 2021 then sends the processed data to the driver controller 2029 or to frame buffer 2028 for storage. Raw data typically refers to the information that identifies the image characteristics at each location within an image. For example, such image characteristics can include color, saturation, and gray-scale level.

In one embodiment, the processor 2021 includes a microcontroller, CPU, or logic unit to control operation of the exemplary display device 2040. Conditioning hardware 2052 generally includes amplifiers and filters for transmitting signals to the speaker 2045, and for receiving signals from the microphone 2046. Conditioning hardware 2052 may be discrete components within the exemplary display device 2040, or may be incorporated within the processor 2021 or other components.

The driver controller 2029 takes the raw image data generated by the processor 2021 either directly from the processor 2021 or from the frame buffer 2028 and reformats the raw image data appropriately for high speed transmission to the array driver 2022. Specifically, the driver controller 2029 reformats the raw image data into a data flow having a raster-like format, such that it has a time order suitable for scanning across the display array 2030. Then the driver controller 2029 sends the formatted information to the array driver 2022. Although a driver controller 2029, such as a LCD controller, is often associated with the system processor 2021 as a stand-alone Integrated Circuit (IC), such controllers may be implemented in many ways. They may be embedded in the processor 2021 as hardware, embedded in the processor 2021 as software, or fully integrated in hardware with the array driver 2022.

Typically, the array driver 2022 receives the formatted information from the driver controller 2029 and reformats the video data into a parallel set of waveforms that are applied many times per second to the hundreds and sometimes thousands of leads coming from the display's x-y matrix of pixels.

In one embodiment, the driver controller 2029, array driver 2022, and display array 2030 are appropriate for any of the types of displays described herein. For example, in one embodiment, driver controller 2029 is a conventional display controller or a bi-stable display controller (e.g., an interferometric modulator controller). In another embodiment, array driver

2022 is a conventional driver or a bi-stable display driver (e.g., an interferometric modulator display). In one embodiment, a driver controller 2029 is integrated with the array driver 2022. Such an embodiment is common in highly integrated systems such as cellular phones, watches, and other small area displays. In yet another embodiment, display array 2030 is a typical display array or a bi-stable display array (e.g., a display including an array of interferometric modulators).

The input device 2048 allows a user to control the operation of the exemplary display device 2040. In one embodiment, input device 2048 includes a keypad, such as a QWERTY keyboard or a telephone keypad, a button, a switch, a touch-sensitive screen, a pressure- or heat-sensitive membrane. In one embodiment, the microphone 2046 is an input device for the exemplary display device 2040. When the microphone 2046 is used to input data to the device, voice commands may be provided by a user for controlling operations of the exemplary display device 2040.

Power supply 2050 can include a variety of energy storage devices as are well known in the art. For example, in one embodiment, power supply 2050 is a rechargeable battery, such as a nickel-cadmium battery or a lithium ion battery. In another embodiment, power supply 2050 is a renewable energy source, a capacitor, or a solar cell, including a plastic solar cell, and solar-cell paint. In another embodiment, power supply 2050 is configured to receive power from a wall outlet.

In some implementations control programmability resides, as described above, in a driver controller which can be located in several places in the electronic display system. In some cases control programmability resides in the array driver 2022. Those of skill in the art will recognize that the above-described optimization may be implemented in any number of hardware and/or software components and in various configurations.

While the above detailed description has shown, described, and pointed out novel features of the invention as applied to various embodiments, it will be understood that various omissions, substitutions, and changes in the form and details of the device or process illustrated may be made by those skilled in the art without departing from the spirit of the invention. As one example, it will be appreciated that the test voltage driver circuitry could be separate from the array driver circuitry used to create the display. As with current sensors, separate voltage sensors could be dedicated to separate row electrodes. The scope of the invention is indicated by the appended claims rather than by the foregoing description. All changes which come within the meaning and range of equivalency of the claims are to be embraced within their scope.

The invention claimed is:

1. A method of determining one or both of an actuation voltage and a release voltage of a microelectromechanical device, the method comprising:
 - applying at least two different electric potentials to at least one electrode coupled to said device;
 - detecting at least one capacitance dependent response of said device at said at least two different electric potentials;
 - determining, based at least in part on said response, a state of said device at said at least two different electric potentials; and
 - determining one or both of said actuation voltage and release voltage based at least in part on said determining a state of said device.
2. The method of claim 1, wherein said determining comprises determining whether said response is greater than a threshold.
3. The method of claim 2, wherein said detecting comprises sensing a voltage generated on said electrode.
4. The method of claim 2, wherein said detecting comprises sensing a current flow generated through said pixel.
5. A display system comprising:
 - an array of microelectromechanical pixels configured to present display data to a user of said display system;
 - at least one additional microelectromechanical pixel that is not one of said microelectromechanical pixels configured to present display data; and
 - a sensor, configured to sense an actuated state or a released state or both, of said at least one additional microelectromechanical pixel.
6. The display system of claim 5, wherein said sensor senses a capacitance dependent response of said additional microelectromechanical pixels.
7. The display system of claim 6, wherein said sensors comprise current sensors.
8. The system of claim 5, wherein at least some of said pixels configured to present display data comprise interferometric modulators.
9. The system of claim 5, wherein said sensor comprises a comparator.
10. A method for compensating for shifts in one or both of the release and actuation voltage display pixels, the method comprising:
 - determining the actuation and or release state of at least one pixel; and
 - modifying driving voltage levels in response to said determining.
11. The method of claim 10, wherein said determining comprises determining the

actuation and or release state of a test pixel.

12. A method of compensating for a temperature dependence of a display device, said method comprising determining one or both of an actuation and release voltage for at least one pixel associated with said display device and modifying device operational parameters based at least in part on said determining.

13. The method of claim 12, wherein said determining comprises determining a capacitance dependent electrical response of said at least one pixel.

14. The method of claim 12, wherein said at least one pixel comprises a test pixel that is not part of a viewable display.

15. A display device comprising:
an array of microelectromechanical pixels; at least one test microelectromechanical pixel; and
means for determining one or both of an actuation voltage and release voltage of said test microelectromechanical pixel.

16. The display system of claim 5, wherein said at least one additional micromechanical pixel is separate from said array of micromechanical pixels.

17. The display system of claim 5, wherein said at least one additional micromechanical pixel comprises two or more micromechanical pixels placed around the actual viewing area of the display.

18. The display system of claim 5, wherein said at least one additional micromechanical pixel is fabricated during the same process that produces said array such that the physical characteristics are similar if not essentially identical with the physical characteristics of the pixels in the viewable array.

19. The display system of claim 17, wherein some or all of the sense circuitry is shared among said two or more micromechanical pixels.

20. The display system of claim 17, where said at least one additional micromechanical pixel comprises four micromechanical pixels each being disposed near a corner of said array.

21. A display system comprising:
an array of microelectromechanical pixels configured to present display data to a user of said display system; and
a test circuit configured to apply at least two different electric potentials to at least one electrode coupled to a microelectromechanical pixel in said array, detect at least one capacitance dependent response of said device at said at least two different electric potentials, determine based at least in part on said response, a state of said device at said at least two different electric potentials, and determine one or both of said actuation

voltage and release voltage based at least in part on said determining a state of said device.